



USRON.109DC1D1

PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant : Gary Chen et al.
Appl. No. : 10/614,538
Filed : July 3, 2003
For : SEMICONDUCTOR
STRUCTURE WITH
SUBSTANTIALLY ETCHED
OXYNITRIDE DEFECTS
PROTRUDING THEREFROM
Examiner : Dolan, Jennifer M.
Group Art Unit : 2813

CERTIFICATE OF MAILING

I hereby certify that this correspondence and all marked attachments are being deposited with the United States Postal Service as first-class mail in an envelope addressed to: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450, on

3/7/05
(Date)
John R. King
John R. King, Reg. No. 34,362

AMENDMENT ACCOMPANYING REQUEST FOR CONTINUED EXAMINATION
IN RESPONSE TO JANUARY 11, 2005 FINAL OFFICE ACTION

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Dear Sir:

In response to the Final Office Action mailed January 11, 2005, Applicants respectfully submit the following amendments and comments concurrent with a filing of a Request for Continued Prosecution (RCE).

Amendments to the Claims are reflected in the listing of claims, which begins on page 2 of this paper.

Remarks/Arguments begin on page 7 of this paper.